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Vishay Semiconductors

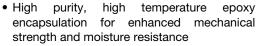
High Performance Schottky Rectifier, 2 x 10 A

Base common cathode cathode Anode VS-20CTQ150SHM3 TO-262AA Base common cathode common cathode cathode vS-20CTQ150SHM3 TO-262AA Base common common cathode common cathode cathode Anode VS-20CTQ150-1HM3

PRINMARY CHARACTERISTICS					
Package	D ² PAK (TO-263AB), TO-262AA				
I _{F(AV)}	2 x 10 A				
V_{R}	150 V				
V _F at I _F	0.66 V				
I _{RM} max.	5.0 mA at 125 °C				
T_J max.	175 °C				
E _{AS}	1.0 mJ				
Diode variation	Common cathode				

FEATURES

- 175 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High frequency operation





FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD-201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	20	A				
V _{RRM}		150	V				
I _{FSM}	t _p = 5 μs sine	1030	А				
V _F	10 A _{pk} , T _J = 125 °C (per leg)	0.66	V				
T _J	Range	-55 to +175	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-20CTQ150SHM3 UNITS							
Maximum DC reverse voltage	V_{R}	150	V				
Maximum working peak reverse voltage	V_{RWM}	130	V				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDI	TEST CONDITIONS		UNITS	
Maximum average forward per leg current See fig. 5 per device			50.0/ d.l. a.da al T. 454.00		10		
		I _{F(AV)}	50 % duty cycle at T_C = 154 °C, rectangular waveform		20		
Maximum peak one cycle			5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	1030	A	
non-repetitive surge current per leg See fig. 7		IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	180		
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}$, $I_{AS} = 1 \text{A}$, $L = 2 \text{mH}$		1.0	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	Α	



VS-20CTQ150SHM3, VS-20CTQ150-1HM3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS	
		10 A	T _{.1} = 25 °C	0.80	0.88	V	
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.90	1.0		
		10 A	T _{.1} = 125 °C	0.63	0.66		
		20 A	1j = 125 C	0.73	0.77		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	3.0	25	μA	
See fig. 2		T _J = 125 °C	v _R = nated v _R	2.7	5.0	mA	
Typical junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		-	280	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		-	8.0	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C		
Maximum thermal resistance,	per leg	В	DC aparation	2.0			
junction to case	per package	R _{thJC} DC operation	1.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-262)	0.50	5,11		
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque — maximum				12 (10)	(lbf \cdot in)		
Madisardata			Case style D ² PAK (TO-263AB)	20CTQ150SH			
Marking device			Case style TO-262	20CTQ1	50-1H		

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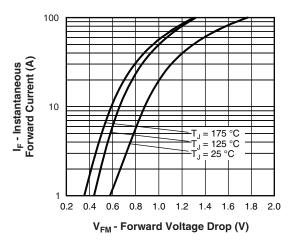


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

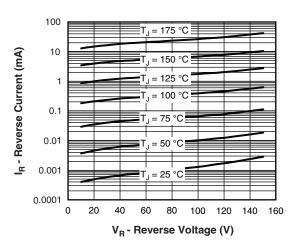


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

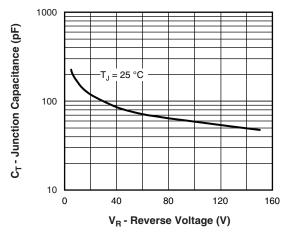


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

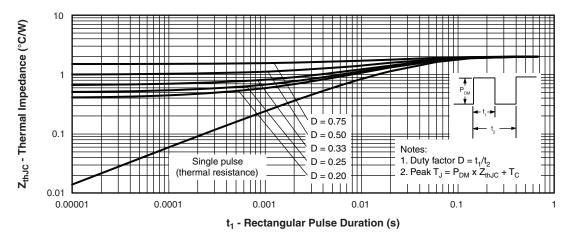


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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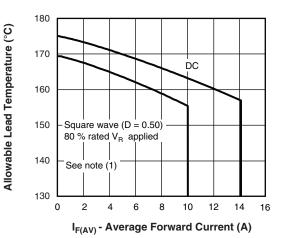


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

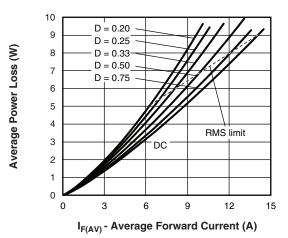


Fig. 6 - Maximum Average Forward Dissipation vs. Average Forward Current

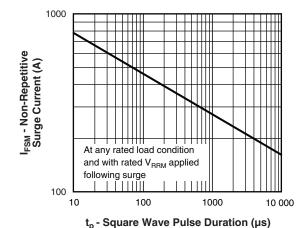


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

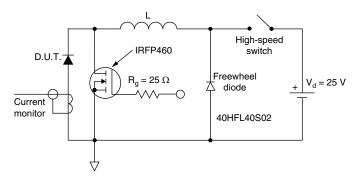


Fig. 8 - Unclamped Inductive Test Circuit

Note

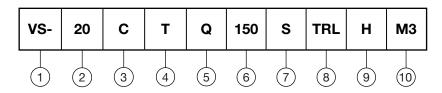
 $\begin{array}{ll} \text{(1)} \;\; \text{Formula used:} \; T_C = T_J - (\text{Pd} + \text{Pd}_{\text{REV}}) \times R_{\text{thJC}}; \\ \text{Pd} = \text{Forward power loss} = I_{\text{F(AV)}} \times V_{\text{FM}} \; \text{at} \; (I_{\text{F(AV)}}/D) \; (\text{see fig. 6}); \\ \text{Pd}_{\text{REV}} = \text{Inverse power loss} = V_{\text{R1}} \times I_{\text{R}} \; (1 - D); \; I_{\text{R}} \; \text{at} \; V_{\text{R1}} = 80 \; \% \; \text{rated} \; V_{\text{R}} \\ \end{array}$

VS-20CTQ150SHM3, VS-20CTQ150-1HM3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

Voltage rating (150 = 150 V)

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - H = AEC-Q101 qualified

- M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20CTQ150SHM3	50	1000	Antistatic plastic tubes			
VS-20CTQ150STRLHM3	800	800	13" diameter reel			
VS-20CTQ150STRRHM3	800	800	13" diameter reel			
VS-20CTQ150-1HM3	50	1000	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS					
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?95046			
Differisions	TO-262AA	www.vishay.com/doc?95419			
Dort marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?95032			



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES SYMBOL MILLIMETERS INCHES		1ES NOTES		MILLIMETERS		HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOIES	STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	METERS	INC	INCHES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC		BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.36	3.71	0.132	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- 5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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